

Fully Integrated Half-Bridge Module



FEATURES

- 20A continuous output current
 - 28A for A-grade
- $\geq 250\text{kHz}$ switching frequency
- 400V supply voltage
- Integrated gate drive with under-voltage lock-out and active Miller clamping

APPLICATIONS

- DC/AC or DC/DC converters
- Motor Drive

DESCRIPTION

The SA110 is a fully integrated half bridge module based on Silicon Carbide technology. The half bridge provides up to 20A continuous output current with microcontroller or DSP control. Protection features include under-voltage lockout (UVLO) function and active Miller clamping.

Figure 1: Module Block Diagram

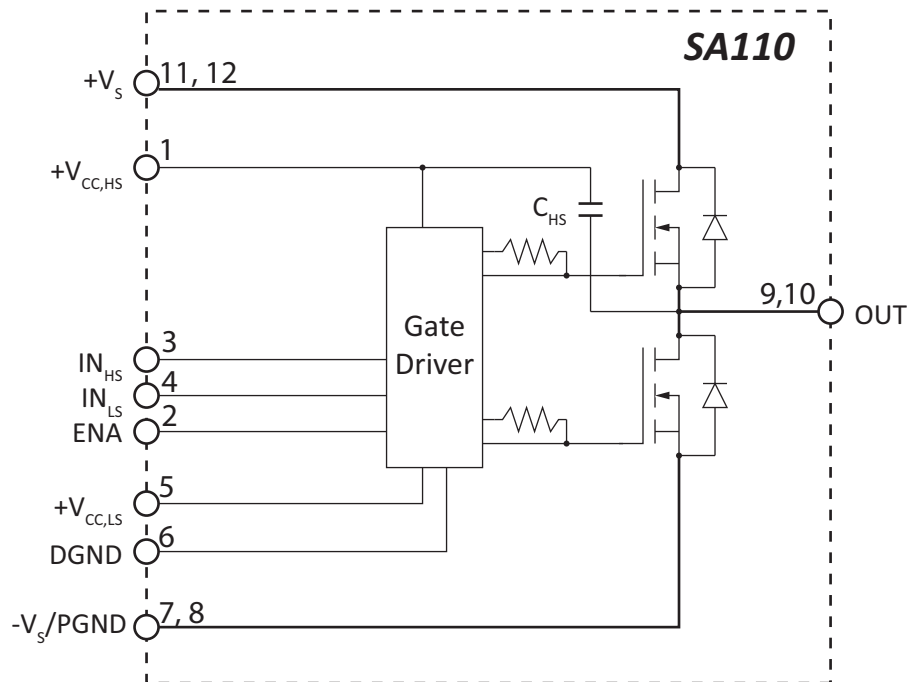
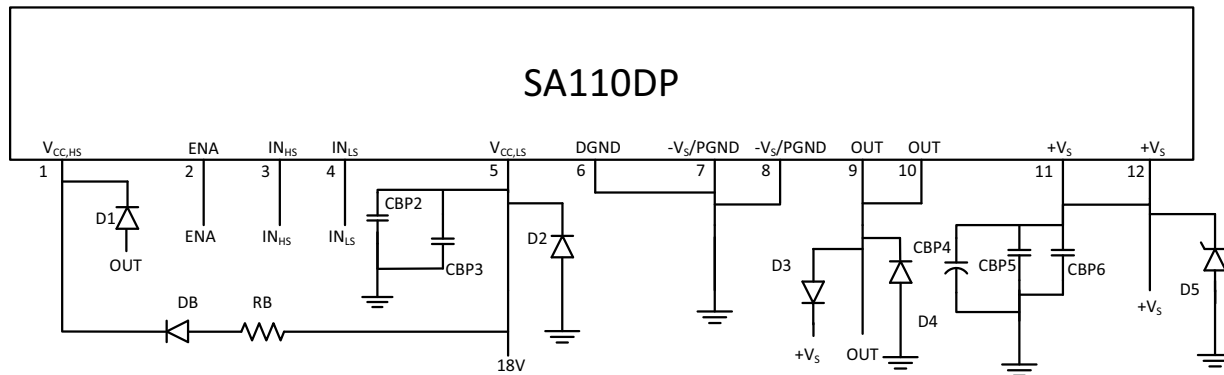


Figure 2: Typical Connection Diagram for Half Bridge Operation



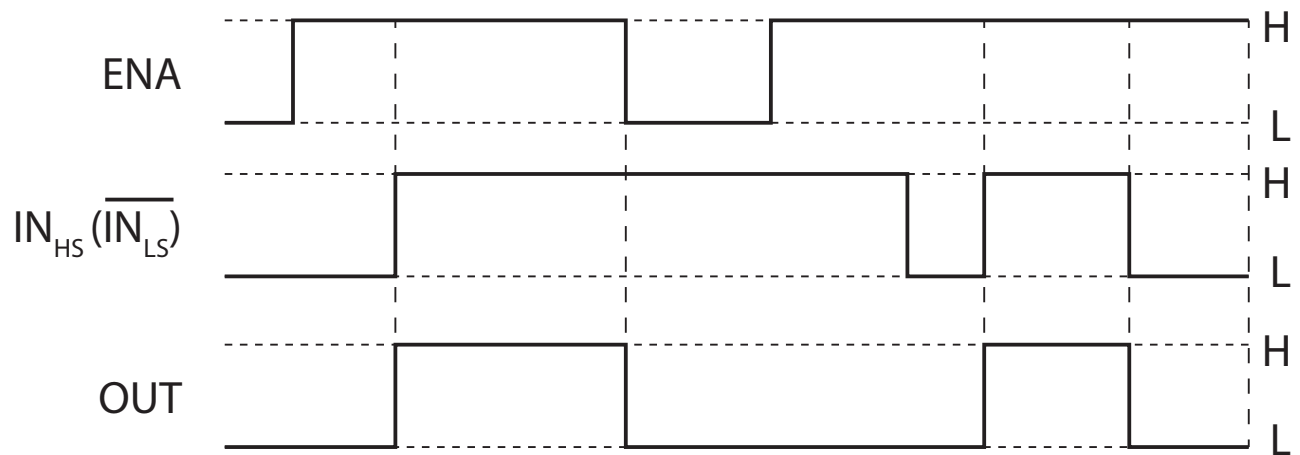
PIN DESCRIPTION TABLE (DP PACKAGE)

Pin Number	Name	Description
1	+V _{CC,HS}	High-side power supply pin
2	ENA	Enable pin. A low level puts the high-side and low-side MOSFETs in high-impedance state. See logic table for details.
3	IN _{HS}	Logic input for high-side SiC MOSFET control
4	IN _{LS}	Logic input for low-side SiC MOSFET control
5	+V _{CC,LS}	Low-side and input side power supply pin
6	DGND	Input side ground pin. This pin needs to be connected externally to the negative supply rail or the power ground
7, 8	-V _S /PGND	Negative supply rail or power ground. When using the Half bridge with positive supply only, connect this pin to power ground and DGND pin. When using the Half bridge in dual supply mode, connect this pin to the negative supply.
9, 10	OUT	PWM output
11, 12	+V _S	Positive supply rail

I/O CONDITION TABLE

ENA	IN _{HS}	IN _{LS}	OUT
L	X	X	High impedance
H	L	L	High impedance
H	H	L	+V _S
H	L	H	-V _S /PGND
H	H	H	High impedance

Figure 3: Input and Output Logic Timing Chart



DEVICE SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Min	Max	Unit
Supply Voltage, total	$+V_S$ to $-V_S$		400	V
Gate Driver Supply Voltage	$+V_{CC}$		22(rel.)	V
Output Current, source, sink, peak, within SOA			40	A
Output Current, continuous, SA110			20	A
Output Current, continuous, SA110A			28	A
Power Dissipation, internal, continuous, per MOSFET	P_D		89	W
Switching Frequency			400	kHz
Input Voltage, logic level			$+V_{CC,LS}$	V
Temperature, pin solder, 10s max.			260	°C
Temperature, junction, MOSFET	T_J		150	°C
Temperature Range, storage		-55	+125	°C
Operating Temperature Range, case	T_C	-40	+125	°C

POWER SUPPLY (SINGLE RAIL SUPPLY)

Parameter	Test Conditions	Min	Typ	Max	Units
Low Side Supply Voltage, $+V_{CC,LS}$ ¹		12	18	20	V
Supply Voltage, $+V_S$				400	V
High Side Supply Voltage, $+V_{CC,HS}$ ²		OUT+12	OUT+18	OUT+20	V
DGND			0		

1. The maximum current might be limited at low temperatures around -25°C when operating the device at $V_{CC}<14V$.
2. The high-side supply should be realized either as a floating voltage supply relative to the device output or as a bootstrap circuit (resistor and diode in series between $+V_{CC,LS}$ and $+V_{CC,HS}$).

POWER SUPPLY (DUAL RAIL SUPPLY)

Parameter	Test Conditions	Min	Typ	Max	Units
Low Side Supply Voltage, $+V_{CC,LS}$ ¹		$-V_S+12$	$-V_S+18$	$-V_S+20$	V
Total Supply Voltage, $+V_S-(-V_S)$				400	V
High Side Supply Voltage, $+V_{CC,HS}$ ²		OUT+12	OUT+18	OUT+20	V
DGND			$-V_S$		

1. The maximum current might be limited at low temperatures around -25°C when operating the device at $V_{CC}<14V$.
2. The high-side supply needs to be a floating supply relative to the device output (or a bootstrap circuit if suitable). The low-side supply voltage is relative to the negative supply rail.

INPUT

Parameter	Test Conditions	Min	Typ	Max	Units
Logic High Level Input Voltage		DGND+2.0		$+V_{CC,LS}$	V
Logic Low Level Input Voltage		DGND		1.1	V
Isolation			450	DGND+0.8	V

OUTPUT

Parameter	Test Conditions	SA110			SA110A			Units
		Min	Typ	Max	Min	Typ	Max	
RDS(ON), per MOSFET ¹	I _D =27A, V _{CC} =18V, T _J =25°C		30			*		mΩ
RDS(ON), per MOSFET ¹	I _D =27A, V _{CC} =18V, T _J =125°C		39.6			*		mΩ
RDS(ON), (Including parasitics)	I _D =27A, V _{CC} =18V, T _J =25°C		73			*		mΩ
Rise Time, per MOSFET			45			*		ns
Fall Time, per MOSFET			30			*		ns
Switching Frequency				400 ²			*	kHz
Current, continuous, source/sink		20			28			A
Current, peak, source/sink				40			*	A
Current, continuous, body diode, per MOSFET		20			28			A
Current, peak, body diode, per MOSFET				40			*	A
Reverse Recovery Time, body diode, per MOSFET	V _S =300V, I _F =27A, di/dt=1100A/μs		26			*		ns

1. MOSFET only. Does not consider resistance due to layout/routing.
2. Although the maximum switching frequency of the SA110 is 400kHz, do not operate the device at 400kHz at full supply voltage while sourcing/sinking maximum output current because of high switching and conduction losses.

THERMAL SPECS

Parameter	Test Conditions	SA110			Units
		Min	Typ	Max	
Resistance, Junction to case	F < 60Hz			1.4	°C/W
Resistance, Junction to case	F ≥ 60Hz			1.1	°C/W
Resistance, Junction to air			30		°C/W
Temperature Range, Case		-40		125	°C

Figure 4: Power Derating

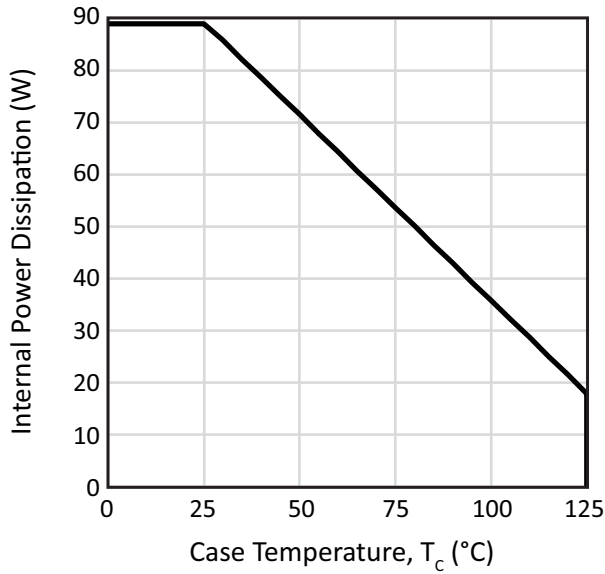


Figure 5: Output Current vs. Temperature

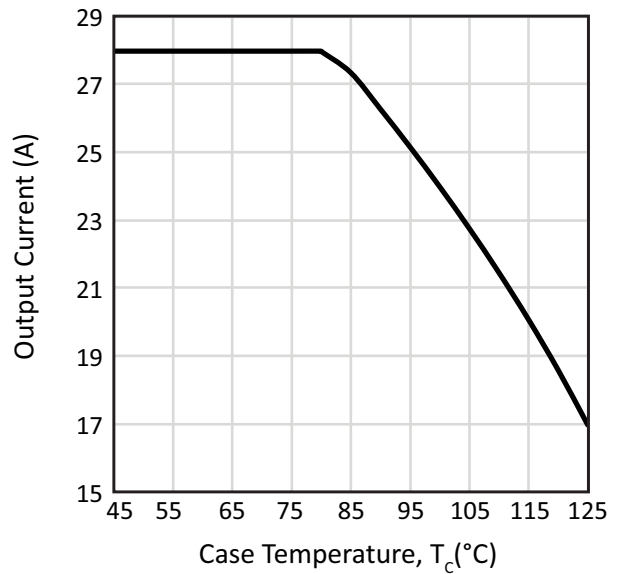


Figure 6: Flyback Current vs. Reverse Voltage

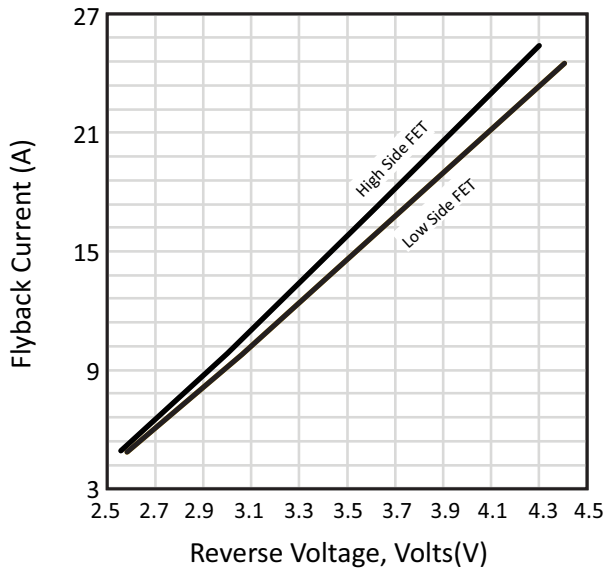


Figure 7: $R_{DS(ON)}$ vs. Temperature

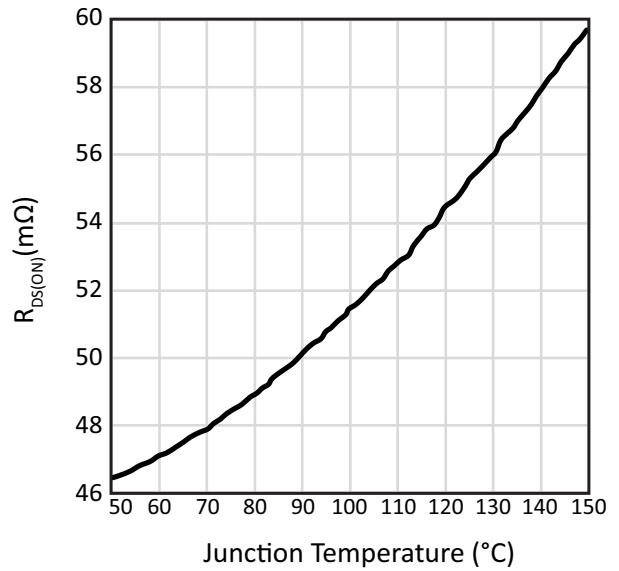


Figure 8: Output Voltage vs. Output Current (Low Side FET)

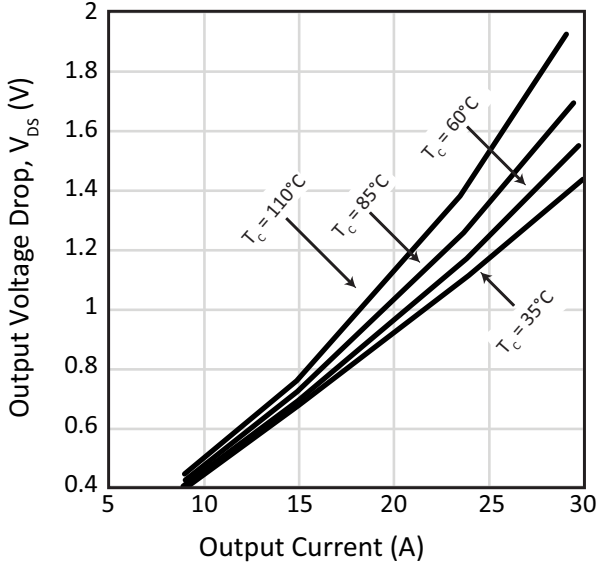


Figure 9: Output Voltage Drop vs. Output Current (High Side FET)

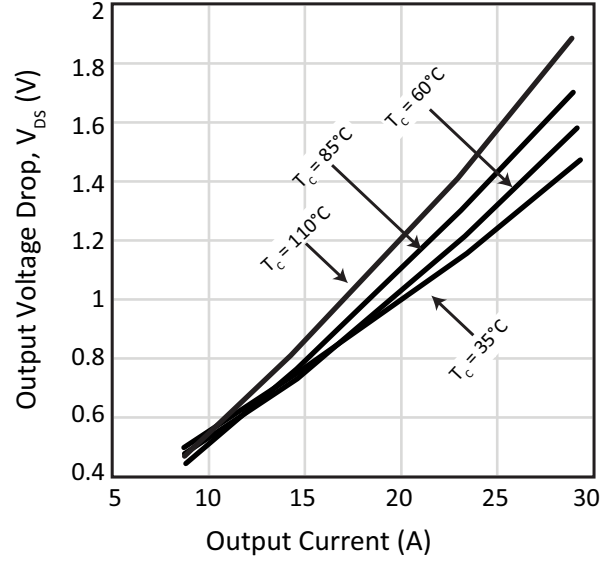


Figure 10: Switching Energy vs. Supply Voltage

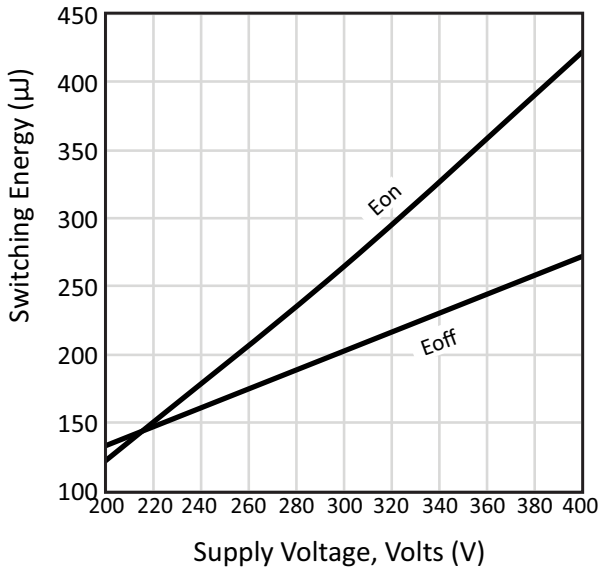
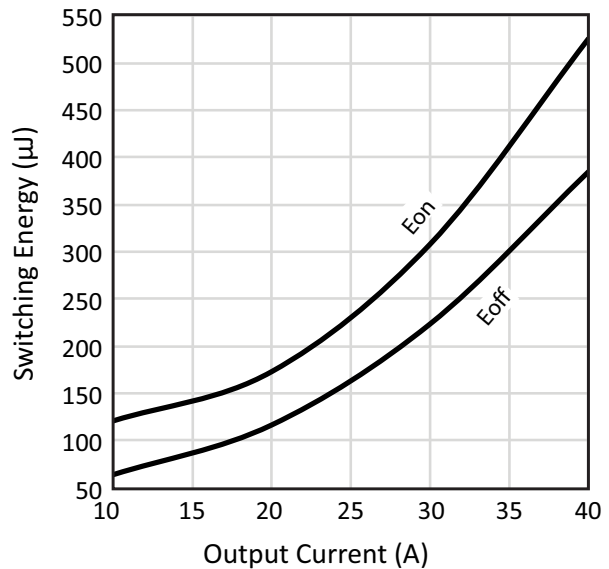


Figure 11: Switching Energy vs. Current



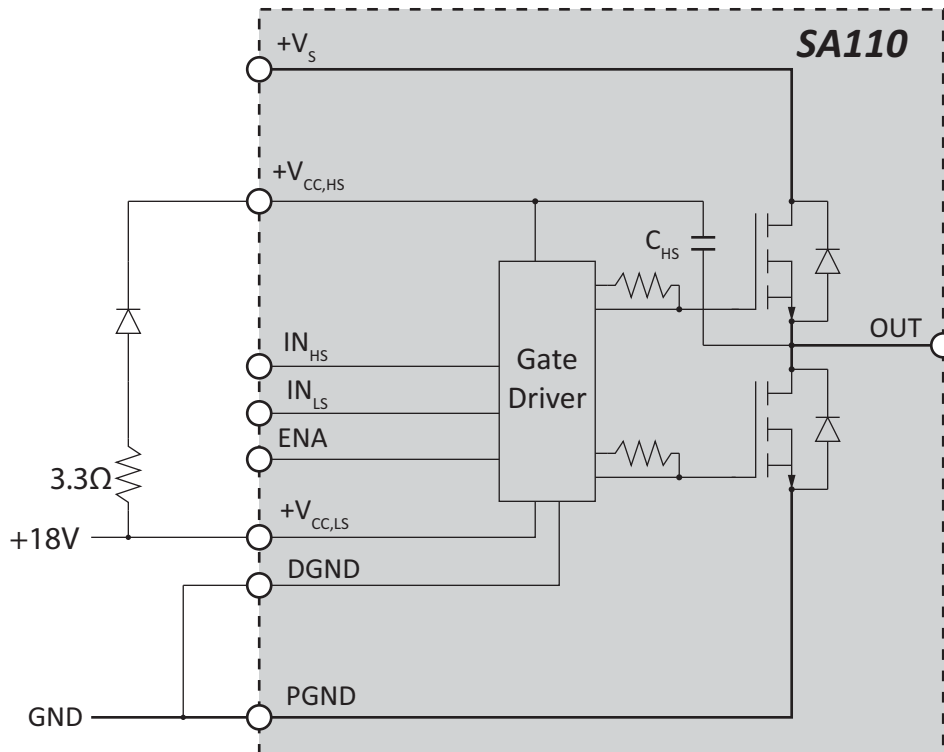
GENERAL

Please read Application Note 1 "General Operating Considerations" which covers stability, supplies, heat sinking, mounting, current limit, SOA interpretation, and specification interpretation. Visit www.apexanalog.com for Apex Microtechnology's complete Application Notes library, Technical Seminar Workbook, and Evaluation Kits.

BOOTSTRAP CIRCUIT

When operating the device with Single Supply Rail, at the high-side supply voltage ($V_{CC,HS}$) can be realized through a bootstrap circuit if operating the device at 100% duty cycle is not required. Figure 12 illustrates the components required for the bootstrap circuit. The high-side supply voltage is connected to the low-side supply voltage through a resistor and a diode that are put in series.

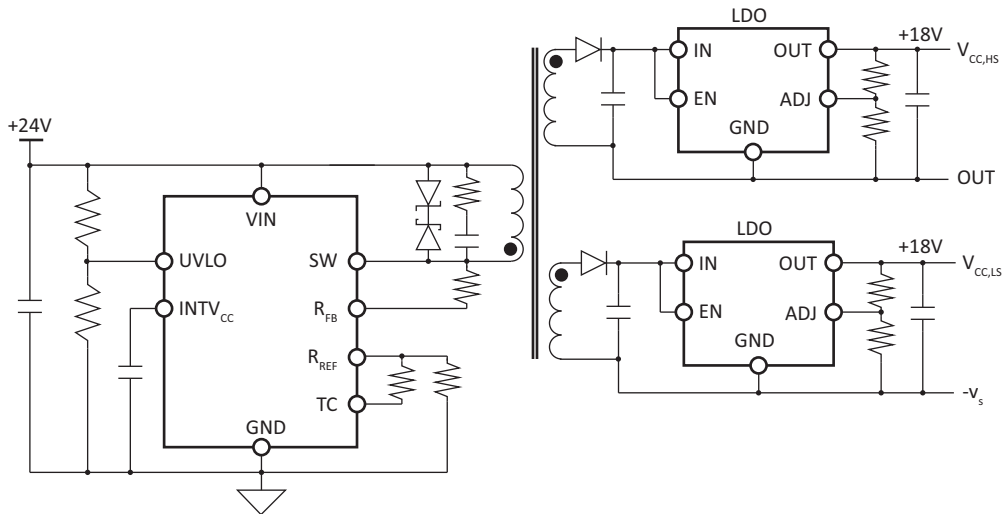
Figure 12: Bootstrap Circuit for Single Supply Rail Operation



POWER SUPPLY FOR DUAL RAIL MODE

In dual rail mode, the low-side gate driver is operating relative to the negative supply rail, which is not ground, but $-V_S$. Dual rail mode is typically used when you switch only one side (high side or low side) during each half period of an output sine wave, so a bootstrap circuit for the high-side is also not suitable. Figure 13 shows a simplified power supply for such condition. It is a fly-back converter circuit with two windings on the secondary side of the transformer.

Figure 13: Power Supply for Dual Rail Mode (Simplified)

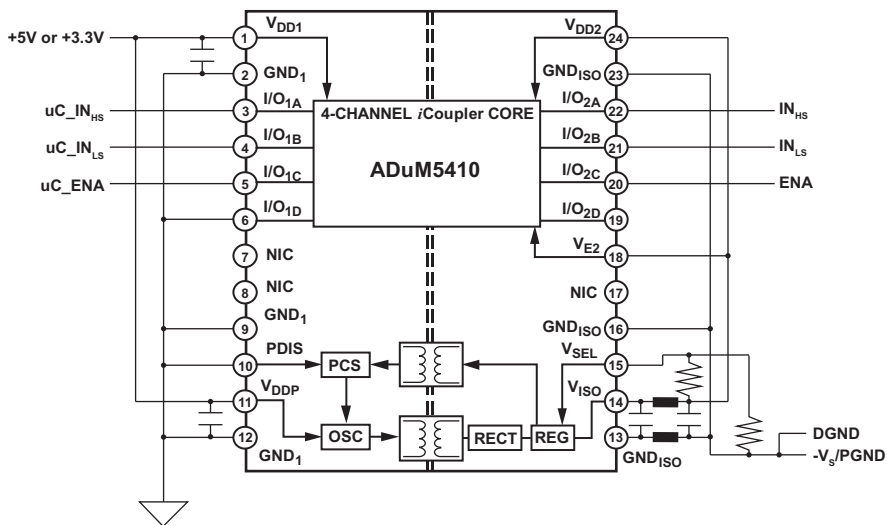


INPUT SIGNAL ISOLATION

When using dual rail mode, the input signals (which are referenced to the system ground) need to be level shifted relative to the $-V_S$ supply. The isoPower devices from Analog Devices are well suited to do that level shifting.

The same circuit also can be used when full isolation of the input signals to the SA110 is desired.

Figure 14: Input Signal Isolation (Example using ADuM5410)



UNDER-VOLTAGE LOCKOUT FUNCTION

The SA110 has a built-in under-voltage lockout function. When the $V_{CC,HS}$ or $V_{CC,LS}$ drops below approximately 9V, the output pin will be high impedance. When the supply voltages rise above approximately 10V, the output will return back to normal operating mode. In addition, to prevent malfunctions due to noise, a mask time of approximately 2.5 μ s is set on both high side supply voltages.

BYPASSING

Adequate bypassing of the power supplies is required for proper operation. Failure to do so can cause erratic and low efficiency operation as well as excessive ringing at the outputs. The V_S supply should be bypassed with at least a 1 μ F ceramic capacitor in parallel with another low ESR capacitor of a least 10 μ F per amp of output current. Capacitor types rated for switching applications are the only types that should be considered. The 1 μ F ceramic capacitor must be physically connected directly to the $\pm V_S$ and POWER GND pins. Even one inch of lead length will cause excessive ringing at the outputs. This is due to the very fast switching times and the inductance of the lead connection. The bypassing requirements of the V_{CC} supply are less stringent, but still necessary. A 0.1 μ F to 0.47 μ F ceramic capacitor connected directly to the $V_{CC,LS}$ and $V_{CC,HS}$ pins will suffice.

POWER SUPPLY PROTECTION

Unidirectional transient Voltage suppressors are recommended as protection on the supply pins as shown in figure 2. TVS diodes clamp transients to voltages within the power supply rating and clamp power supply reversals to ground. Whether the TVS diodes are used or not, the system power supply should be evaluated for transient performance including power-on overshoot and power-off polarity reversal as well as line regulation. Conditions which can cause open circuits or polarity reversals on either power supply rail should be avoided or protected against. Unidirectional TVS diodes prevent this, and it is desirable that they be both electrically and physically as close to the amplifier as possible.

OUTPUT PROTECTION

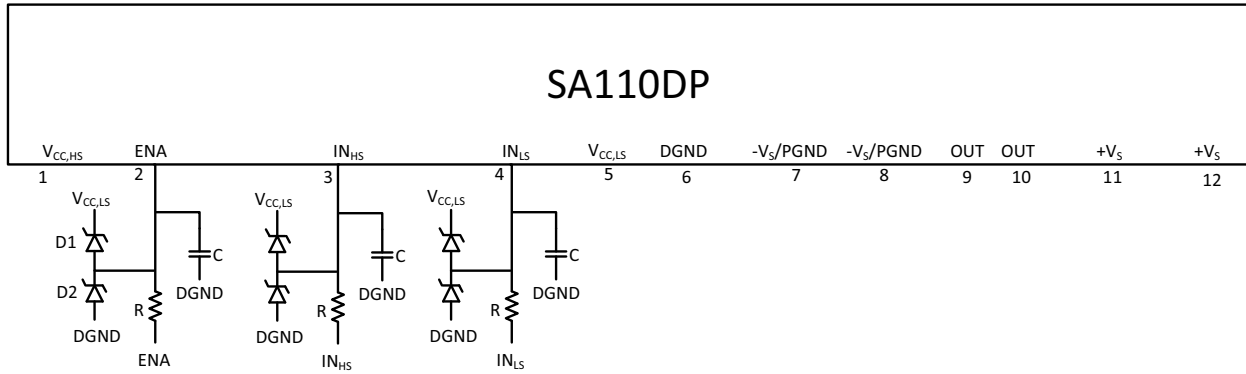
Two external diodes as shown in figure 2, are required to protect these amplifiers from flyback (kickback) pulses exceeding the supply voltages of the amplifier when driving inductive loads. For component selection, these external diodes must be very quick, such as ultra fast recovery diodes with no more than 200 nanoseconds of reverse recovery time. The diode will turn on to divert the flyback energy into the supply rails thus protecting the output transistors from destruction due to reverse bias.

A note of caution about the supply. The energy of the flyback pulse must be absorbed by the power supply. As a result, a transient will be superimposed on the supply voltage, the magnitude of the transient being a function of its transient impedance and current sinking capability. If the supply voltage plus transient exceeds the maximum supply rating or if the AC impedance of the supply is unknown, it is best to clamp the output and the supply with a zener diode to absorb the transient.

INPUT PROTECTION

It is recommended to connect two Schottky diodes at the ENA, IN_{HS} , IN_{LS} pins to provide external protection for the SA110, as shown in figure 15. A 100pF capacitor (capacitor C) can be connected to ground to provide ESD protection from coaxial cables and other ESD sources. A series resistor (approximately 200 Ω) may be added in series with the input pins to limit excessive current going into pins.

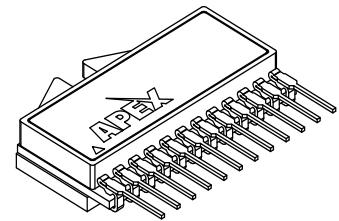
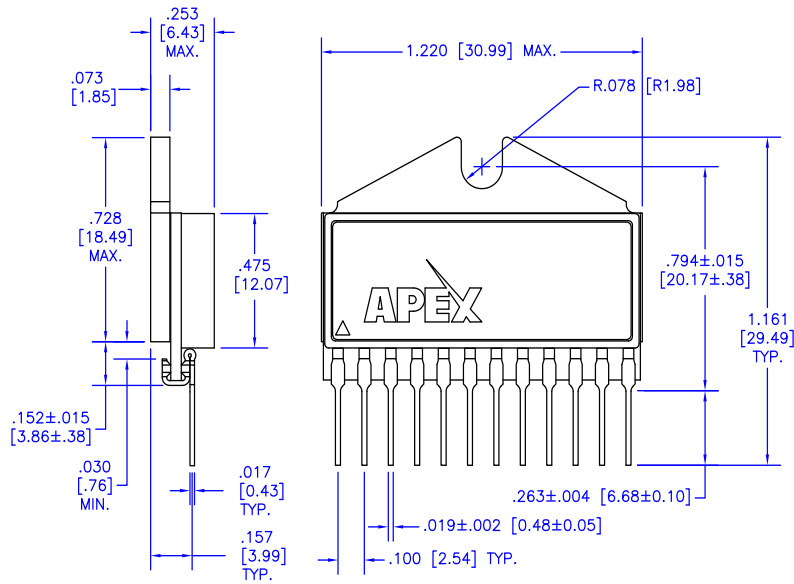
Figure 15: Input Protection



PACKAGE OPTIONS

Part Number	Apex Package Style	Description
SA110DP	DP	12 Pin Power SIP
SA110DPA	DP	12 Pin Power SIP

12-Pin Power SIP DP



NOTES:

1. Dimensions are inches & [mm].
2. Triangle on lid denotes pin 1.
3. Pins: CDA 510 phosphor bronze with tin-lead solder finish
4. Package: Vectra liquid crystal polymer, black
5. Epoxy-sealed & ultrasonically welded non-hermetic package.
6. Package weight: .367 oz. [11.41 g]

Please talk to your Apex representative for package options with bent leads.

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